Notice of Allowability	Application No.	Applicant(s)	
	09/954,515	CHOI ET AL.	
	Examiner	Art Unit	
	Sow-Fun Hon	1772	
The MAILING DATE of this communication apply All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT R of the Office or upon petition by the applicant. See 37 CFR 1.313	(OR REMAINS) CLOSED in or other appropriate commining of the commining of	n this application. If not included unication will be mailed in due course.	
1. 🖾 This communication is responsive to the amendment filed	<u>4/12/07</u> .		
2. X The allowed claim(s) is/are <u>18-20,22-24,26-29 and 31-40</u> .			
3. ☐ Acknowledgment is made of a claim for foreign priority unestable a) ☐ All b) ☐ Some* c) ☐ None of the:		or (f).	
Certified copies of the priority documents have			
Certified copies of the priority documents have	• •		
Copies of the certified copies of the priority do	cuments have been receive	d in this national stage application from	the
International Bureau (PCT Rule 17.2(a)).			
* Certified copies not received:			
Applicant has THREE MONTHS FROM THE "MAILING DATE" noted below. Failure to timely comply will result in ABANDONN THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.		a reply complying with the requiremen	its
4. A SUBSTITUTE OATH OR DECLARATION must be subm INFORMAL PATENT APPLICATION (PTO-152) which give)F
5. CORRECTED DRAWINGS (as "replacement sheets") must	st be submitted.		
(a) ☐ including changes required by the Notice of Draftspers	son's Patent Drawing Review	v (PTO-948) attached	
1) 🔲 hereto or 2) 🔲 to Paper No./Mail Date			
(b) including changes required by the attached Examiner' Paper No./Mail Date	s Amendment / Comment or	in the Office action of	:
Identifying indicia such as the application number (see 37 CFR 1 each sheet. Replacement sheet(s) should be labeled as such in t			:
6. DEPOSIT OF and/or INFORMATION about the depo attached Examiner's comment regarding REQUIREMENT			
Attachment(s)			:
1. Notice of References Cited (PTO-892)	_	formal Patent Application	
2. Notice of Draftperson's Patent Drawing Review (PTO-948)		ummary (PTO-413), Mail Date <u>7/10/07</u> .	
Information Disclosure Statements (PTO/SB/08), Paper No./Mail Date		Amendment/Comment	
Examiner's Comment Regarding Requirement for Deposit of Biological Material	8. 🛭 Examiner's	Statement of Reasons for Allowance	
or biological material	9. ⊠ Other <u>See</u>	Continuation Sheet.	
			:
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Continuation of Attachment(s) 9. Other: The drawings filed 09/17/01 are accepted by the examiner.

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EXAMINER'S AMENDMENT

1. An examiner's amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 CFR 1.312. To ensure consideration of such an amendment, it MUST be submitted no later than the payment of the issue fee.

Authorization for this examiner's amendment was given in a telephone interview with James Fajkowski on July 10, 2007.

The application has been amended as follows:

- 2. Specification: Page 1, Insert as line 1: -- This application is a division of application serial number 09/009,391, filed January 20th, 1998, now US Patent 6,379,509. --
- 3. Claim 28: Line 2: after "the", replace "substrate" with - synthetic resin -.
- 4. Claim 29: Line 13: after "to the", replace "substrate" with - hard coating -.

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Reasons For Allowance

5. The following is an examiner's statement of reasons for allowance.

The closest cited prior art of record, US 5,667,853 fails to fairly teach or suggest, even in view of US 5,508,091, US 4,234,654, US 5,520,952, US 5,750,267 and ITO.

Tin-Doped Indium Oxide for Optical Coating by CERAC Technical Publications, the combination of a substantially transparent electrode assembly comprising: a substrate comprising a synthetic resin; a high index layer formed on the substrate; a conductive layer formed on and disposed adjacent to the high index layer; a high index top layer having a conductivity ranging from about 100 ohms/square to about 400 ohms/square and a thickness of from about 20 nm to about 100 nm formed on the conductive layer; at least the top layer and the conductive layer being patterned so as to divide the conductive layer into a plurality of discrete electrodes; and a layer of silica disposed on the substrate or hard coating adjacent to the substrate, the layer of silica in substantially continuous contact with the substrate or hard coating adjacent to the substrate.

None of the references teach the order of compositional layers wherein a layer of silica is substantially in continuous contact with a substrate that comprises a synthetic resin, or a hard coating adjacent to the substrate that comprises a synthetic resin, and promotes adhesion of the substrate or the hard coating adjacent to the substrate, to a high index layer, in a substantially transparent electrode assembly. See Applicant's arguments in the remarks section dated 04/12/07.

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Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Any inquiry concerning this communication should be directed to Sow-Fun Hon whose telephone number is (571)272-1492. The examiner can normally be reached Monday to Friday from 10:00 AM to 6:00 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Rena Dye, can be reached at (571)272-3186. The fax phone number for the organization where this application or proceeding is assigned is (571)273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Sow-Fun Hon

SUPERVISORY PATENT EXAMINES